

#### SSC139GS6

#### **P-Channel Enhancement Mode MOSFET**

#### > Features

VDS	VGS	RDSON Typ.	ID	
E0V/	±20V	1.8Ω@-10V	0.44	
-50V		2.0Ω@-4V5	-0.4A	

#### > Description

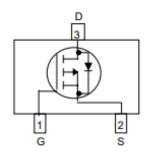
This P-Channel enhancement mode power FETs are produced with high cell density, DMOS trench technology, which is especially used to minimize on-state resistance. This device is particularly suited for low voltage application such as portable equipment, power management and other battery powered circuits and low in-line power loss are needed in a very small outline surface mount package.

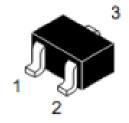
### Applications

- TFT panel power switch
- High side DC/DC Converter
- High side driver for brushless DC motor
- Portable DVD, DPF

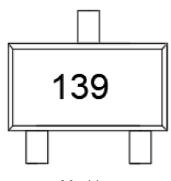
# Pin configuration

Top view





SOT-23



Marking

# > Ordering Information

Device	Package	Shipping	
SSC139GS6	SOT-23	3000/Reel	



# ➤ **Absolute Maximum Ratings**(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit
$V_{DSS}$	Drain-to-Source Voltage	-50	<b>&gt;</b>
$V_{GSS}$	Gate-to-Source Voltage	±20	V
I <sub>D</sub>	Continuous Drain Current <sup>a</sup>	-400	mA
I <sub>DM</sub>	Pulsed Drain Current <sup>b</sup>	-1.0	А
P <sub>D</sub>	Power Dissipation <sup>a</sup>	0.8	W
TJ	Operation junction temperature	-55 to 150	°C
T <sub>STG</sub>	Storage temperature range	-55 to 150	°C

# ➤ Thermal Resistance Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit	
R <sub>θJA</sub>	Junction-to-Ambient Thermal Resistance <sup>a</sup>	144.3	°C/W	

#### Note:

- a. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in² FR-4 board with 2oz.copper,in a still air environment with  $T_A$ =25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t  $\leq$  10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.

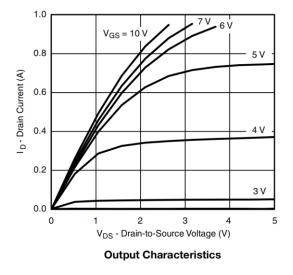


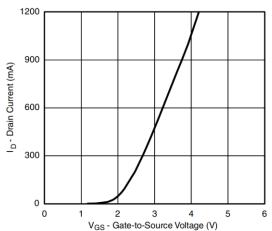
# ➤ Electronics Characteristics(T<sub>A</sub>=25 °C unless otherwise noted)

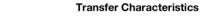
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	VGS=0V,ID=-250uA	-50			V
V <sub>GS (th)</sub>	Gate Threshold Voltage	VDS=VGS,ID=-250uA	-1.0	-1.4	-2.0	V
R <sub>DS(on)</sub>	Drain-Source On- Resistance	VGS=-10V,ID=-0.1A		1.8	5	Ω
		VGS=-5V,ID=-0.1A		2	6	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	VDS=-50V,VGS=0V			-1.5	uA
I <sub>GSS</sub>	Gate-Source leak current	VGS=±20V,VDS=0V			±100	nA
V <sub>SD</sub>	Forward Voltage	VGS=0V,IS=-0.13A		-0.8	-1.3	V
Ciss	Input Capacitance	VDS=-25V, VGS=0V, F=1MHZ		65		
Coss	Output Capacitance			23		pF
Crss	Reverse Transfer Capacitance			16		
$T_{D(ON)}$	Turn-on delay time	VGS=-5V, VDS=-25V, ID=-0.5A, RG=3Ω		12		
Tr	Rise time			6.8		ns
$T_{D(OFF)}$	Turn-off delay time			11.6		
Tf	Fall time			5.6		
$Q_{\mathrm{G}}$	Total Gate Charge	VGS=-5V, VDS=-25V ID=-0.5A		0.8		
Q <sub>GS</sub>	Gate to Source Charge			0.2		nC
$Q_GD$	Gate to Drain Charge			0.3		
Trr	Diode Recovery Time	IF=-1A, di/dt=100A/us, VR=30V		16.2		ns
Qrr	Diode Recovery Charge	IF=-1A, di/dt=100A/us, VR=30V		8		nC

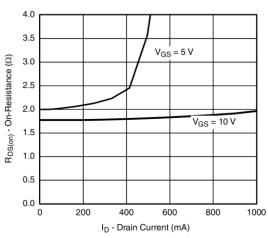


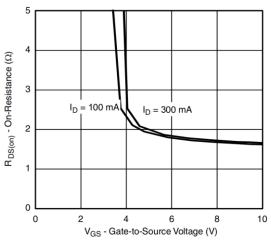
# ➤ Typical Characteristics(T<sub>A</sub>=25°C unless otherwise noted)





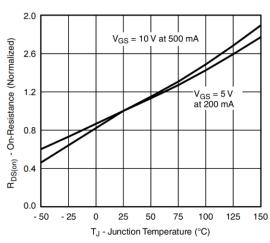


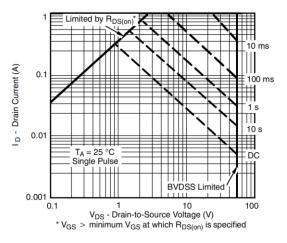




On-Resistance vs. Drain Current

On-Resistance vs. Gate-Source Voltage



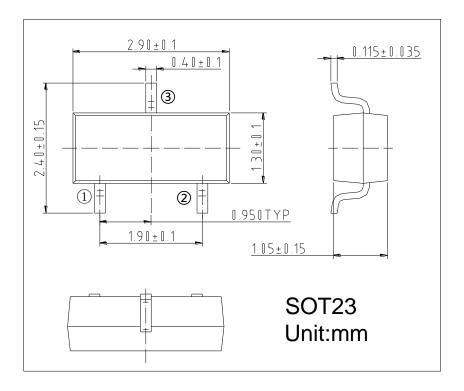


On-Resistance vs. Junction Temperature

Safe Operating Area



# > Package Information



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